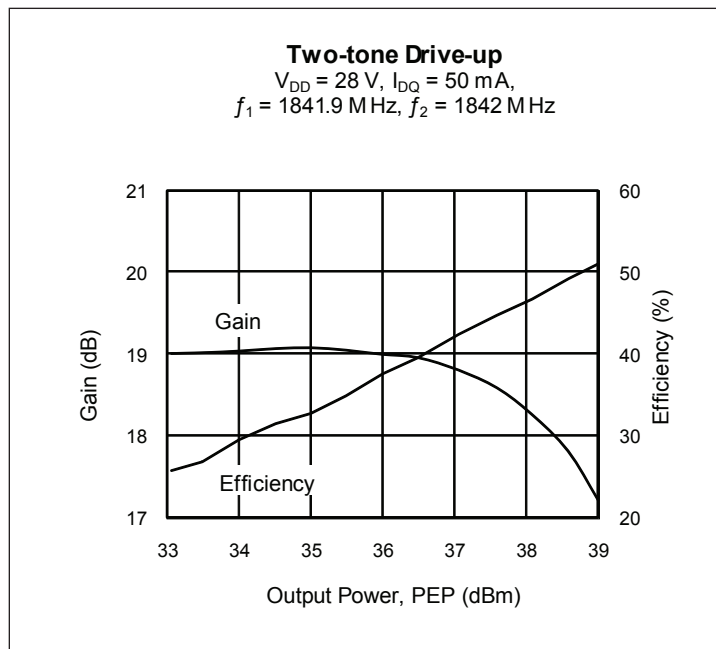


High Power RF LDMOS Field Effect Transistor 4 W, 700 – 2200 MHz

Description

The PTFA220041M is an unmatched 4-watt LDMOS FET intended for power amplifier applications in the 700 MHz to 2200 MHz operating range. This LDMOS device offers excellent gain, efficiency and linearity performance in a small, overmolded plastic package.

PTFA220041M
Package PG-SON-10



Features

- Typical two-carrier WCDMA performance, 1842 MHz, 8 dB PAR
 - $P_{OUT} = 27\text{ dBm Avg}$
 - ACPR = -44 dBc
- Typical CW performance, 1842 MHz, 28 V
 - $P_{OUT} = 37\text{ dBm}$
 - Efficiency = 53.5%
 - Gain = 17.9 dB
- Typical CW performance, 940 MHz, 28 V
 - $P_{OUT} = 37.5\text{ dBm}$
 - Efficiency = 57%
 - Gain = 19.7 dB
- Capable of handling 10:1 VSWR @ 28 V, 5 W (CW) output power
- Integrated ESD protection : Human Body Model, Class 2 (minimum)
- Excellent thermal stability
- Pb-free and RoHS compliant

Two-tone Measurements (not subject to production test - verified by design / characterization in Infineon test fixture)
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 50\text{ mA}$, $P_{OUT} = 4\text{ W PEP}$, $f = 1842\text{ MHz}$, tone spacing = 1 MHz

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	18.5	19	—	dB
Drain Efficiency	η_D	35	37.5	—	%
Intermodulation Distortion	IMD	—	-29	-28	dBc
Input Return Loss	IRL	—	-8	-7	dB

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!

RF Characteristics (cont.)

Two-tone Measurements (not subject to production test - verified by design / characterization in Infineon test fixture)
 $V_{DD} = 28\text{ V}$, $I_{DQ} = 50\text{ mA}$, $P_{OUT} = 5\text{ W PEP}$, $f = 940\text{ MHz}$, tone spacing = 1 MHz

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	—	18.5	—	dB
Drain Efficiency	η_D	—	37	—	%
Intermodulation Distortion	IMD	—	-30	—	dBc
Input Return Loss	IRL	—	-10	—	dB

DC Characteristics

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}$, $I_{DS} = 10\text{ }\mu\text{A}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}$, $V_{GS} = 0\text{ V}$	I_{DSS}	—	—	1.0	μA
On-State Resistance	$V_{GS} = 10\text{ V}$, $V_{DS} = 0.1\text{ A}$	$R_{DS(on)}$	—	2.01	—	Ω
Operating Gate Voltage	$V_{DS} = 28\text{ V}$, $I_{DQ} = 50\text{ mA}$	V_{GS}	2.0	2.5	3.0	V
Gate Leakage Current	$V_{GS} = 10\text{ V}$, $V_{DS} = 0\text{ V}$	I_{GSS}	—	—	1.0	μA

Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	65	V
Gate-Source Voltage	V_{GS}	-0.5 to +12	V
Junction Temperature	T_J	175	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-40 to +150	$^{\circ}\text{C}$
Thermal Resistance ($T_{CASE} = 70^{\circ}\text{C}$, 5 W CW)	$R_{\theta JC}$	5.5	$^{\circ}\text{C/W}$

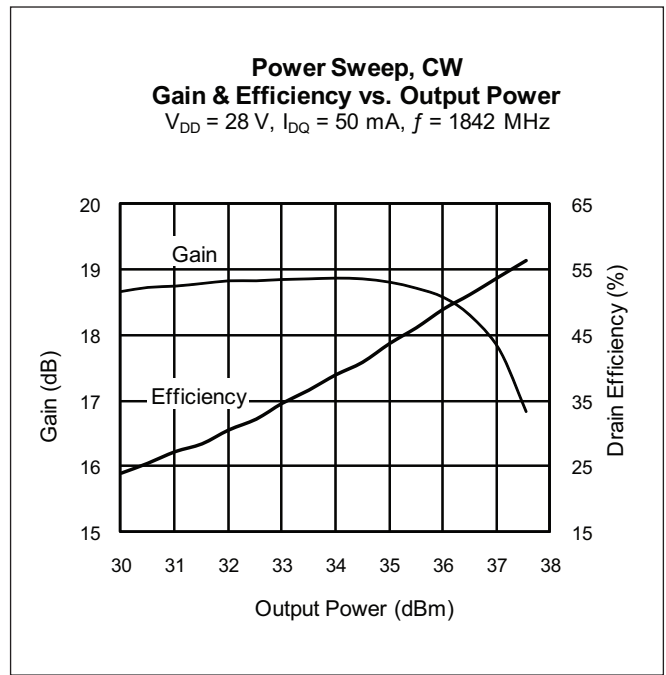
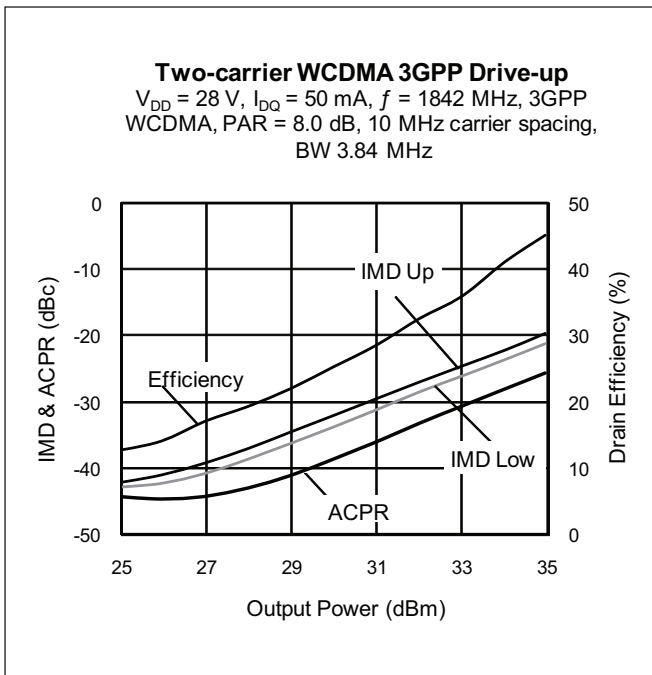
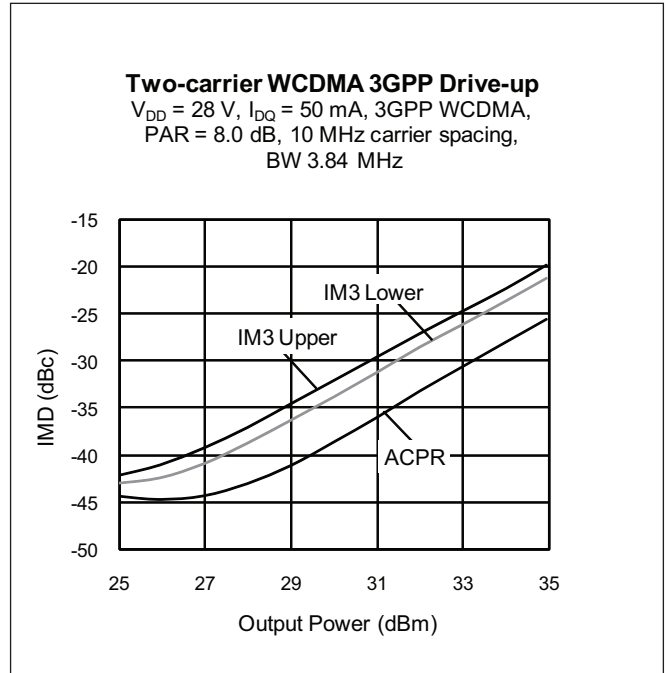
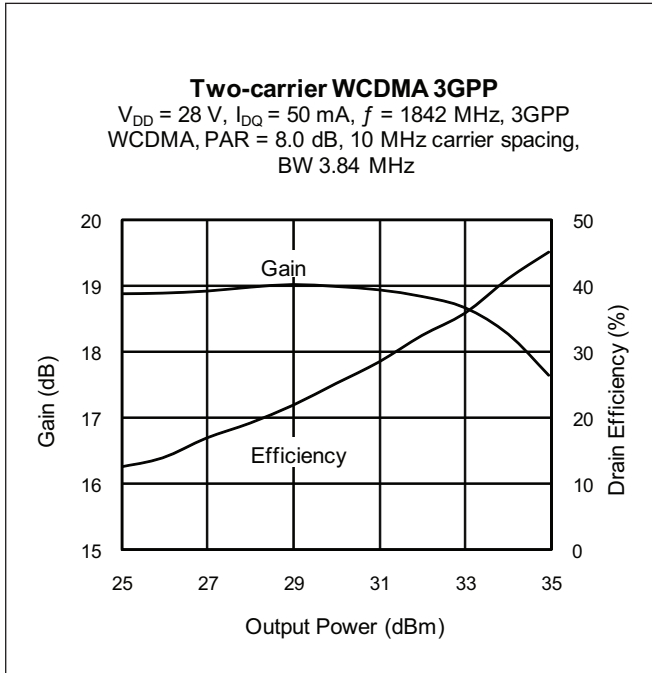
Moisture Sensitivity Level

Level	Test Standard	Package Temperature	Unit
3	IPC/JEDEC J-STD-020	260	$^{\circ}\text{C}$

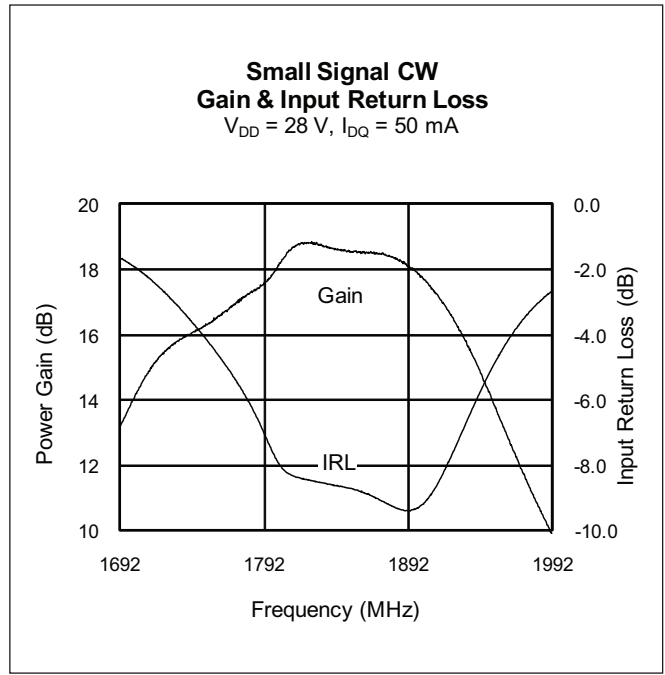
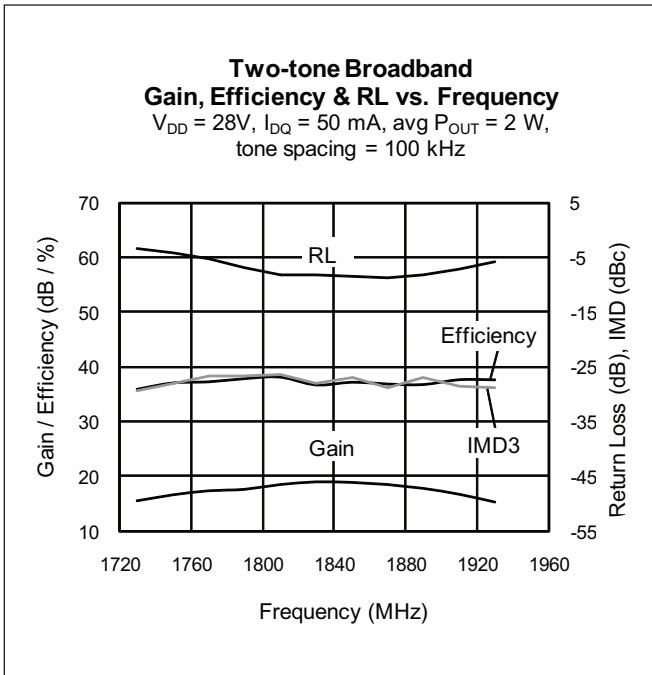
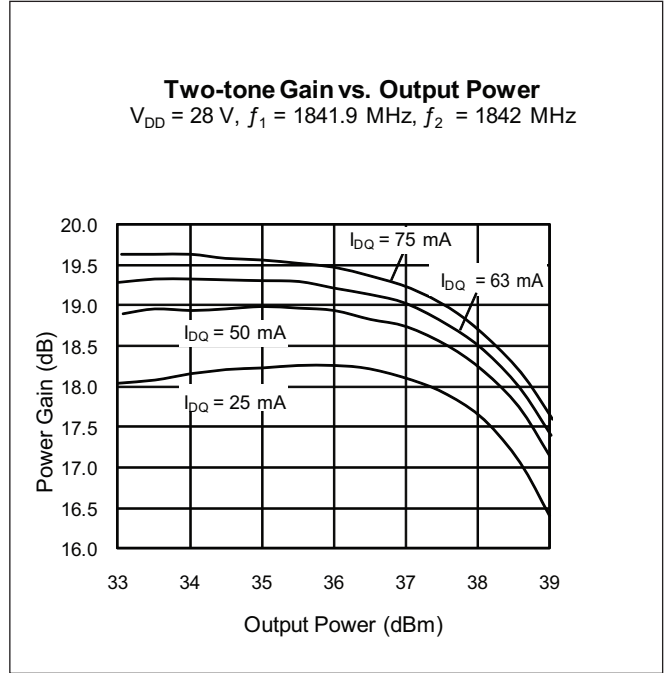
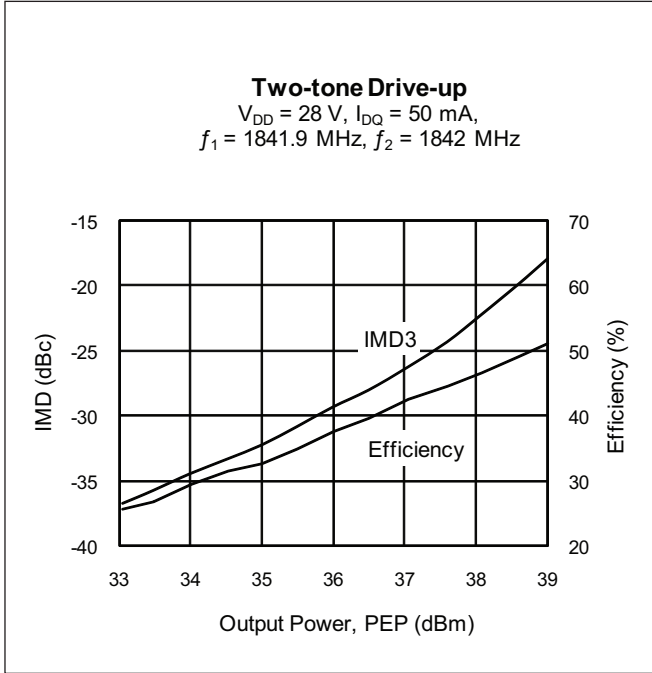
Ordering Information

Type and Version	Package Outline	Package Description	Shipping
PTFA220041M V4	PG-SON-10	Molded plastic, SMD	Tape & Reel, 500 pcs

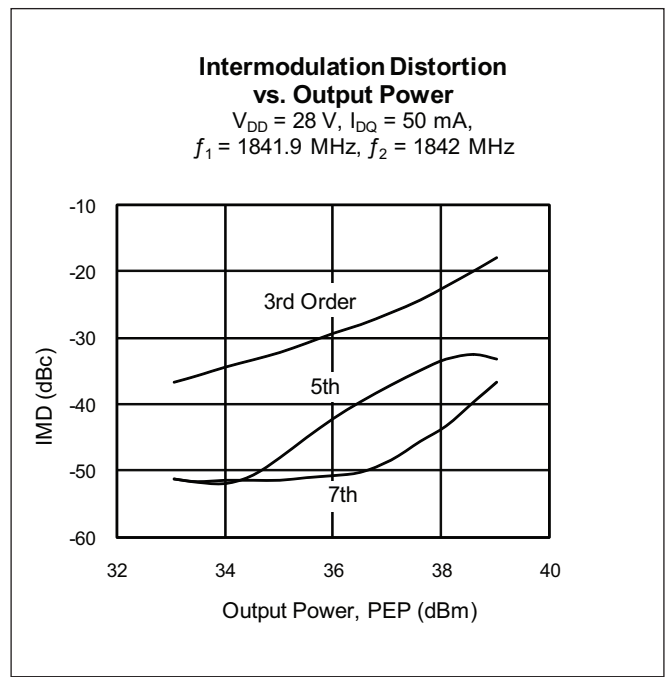
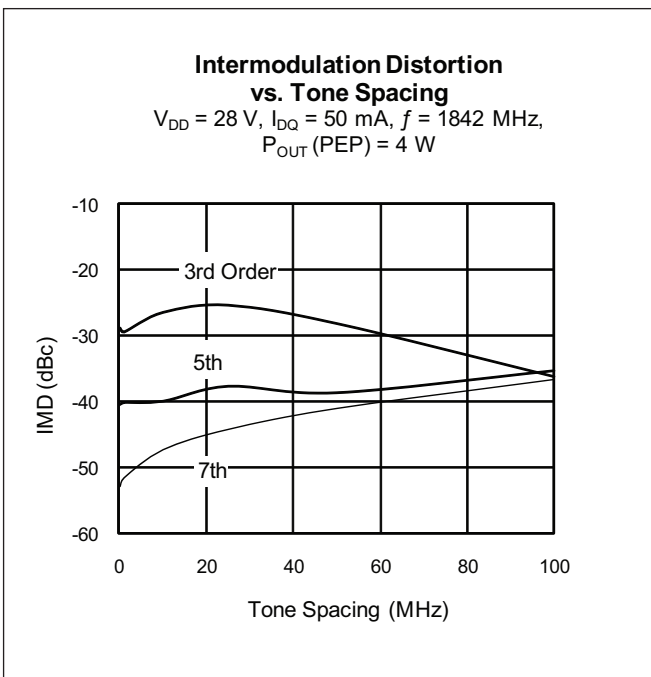
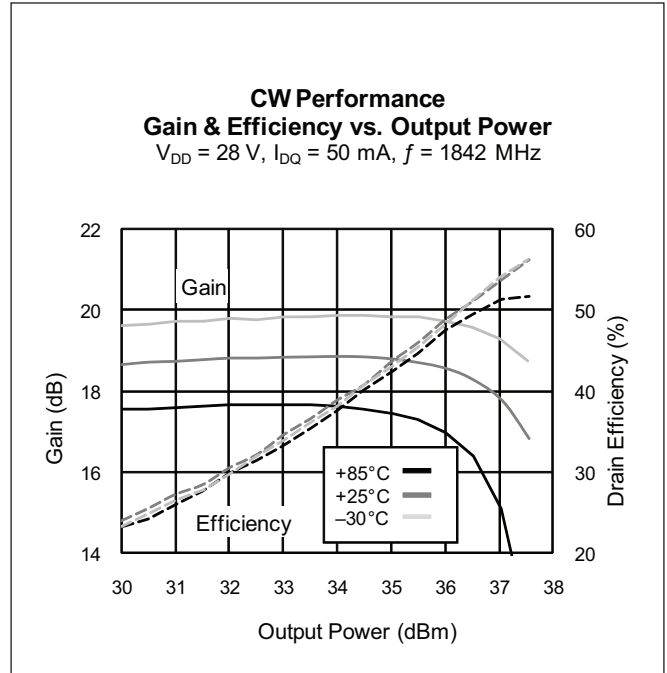
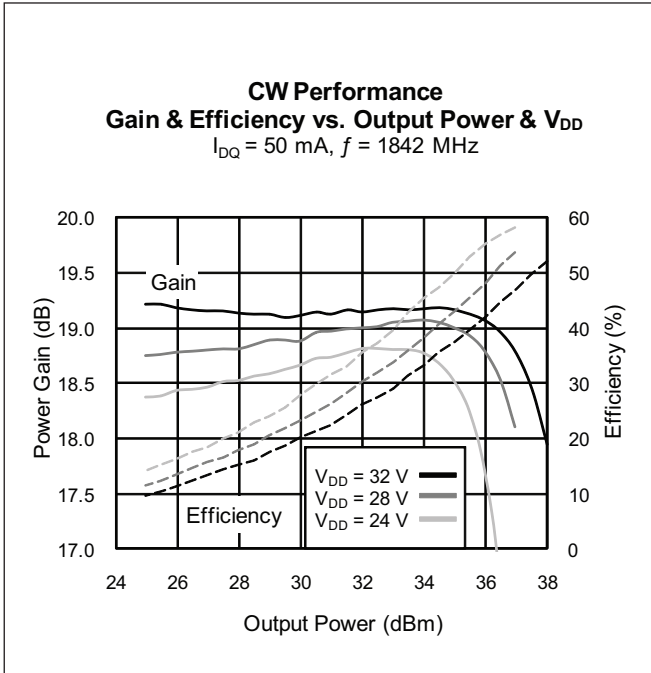
Typical Performance, 1842 MHz (data taken in Infineon test fixture)



Typical Performance, 1842 MHz (cont.)

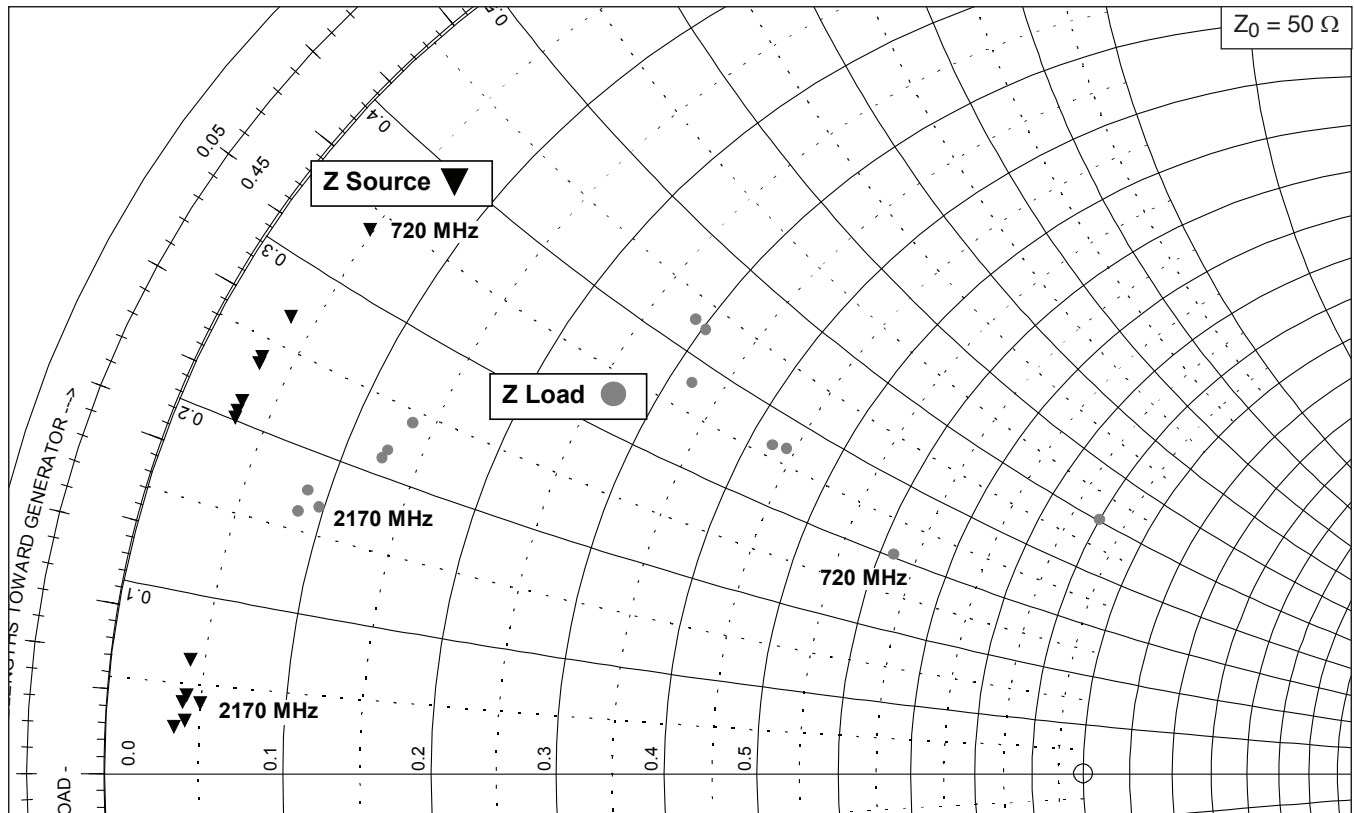
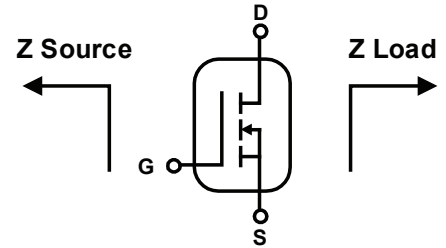


Typical Performance, 1842 MHz (cont.)

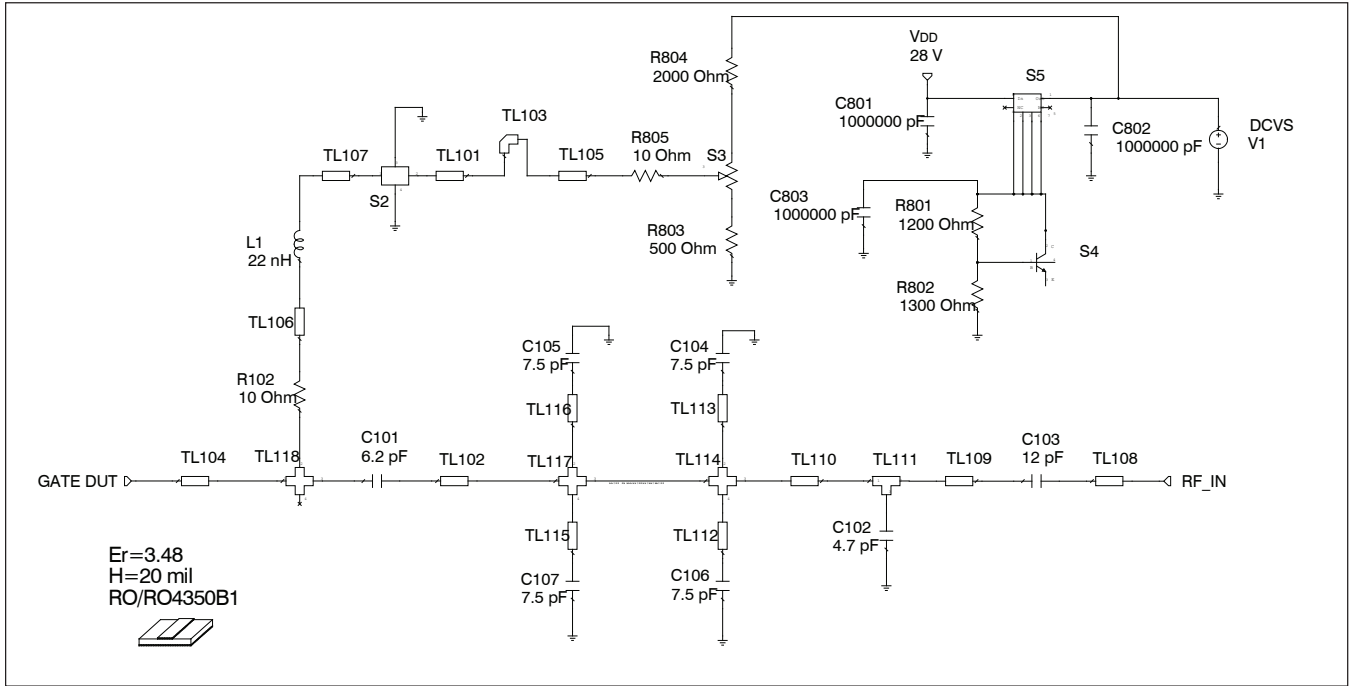


Broadband Circuit Impedance, 1842 MHz

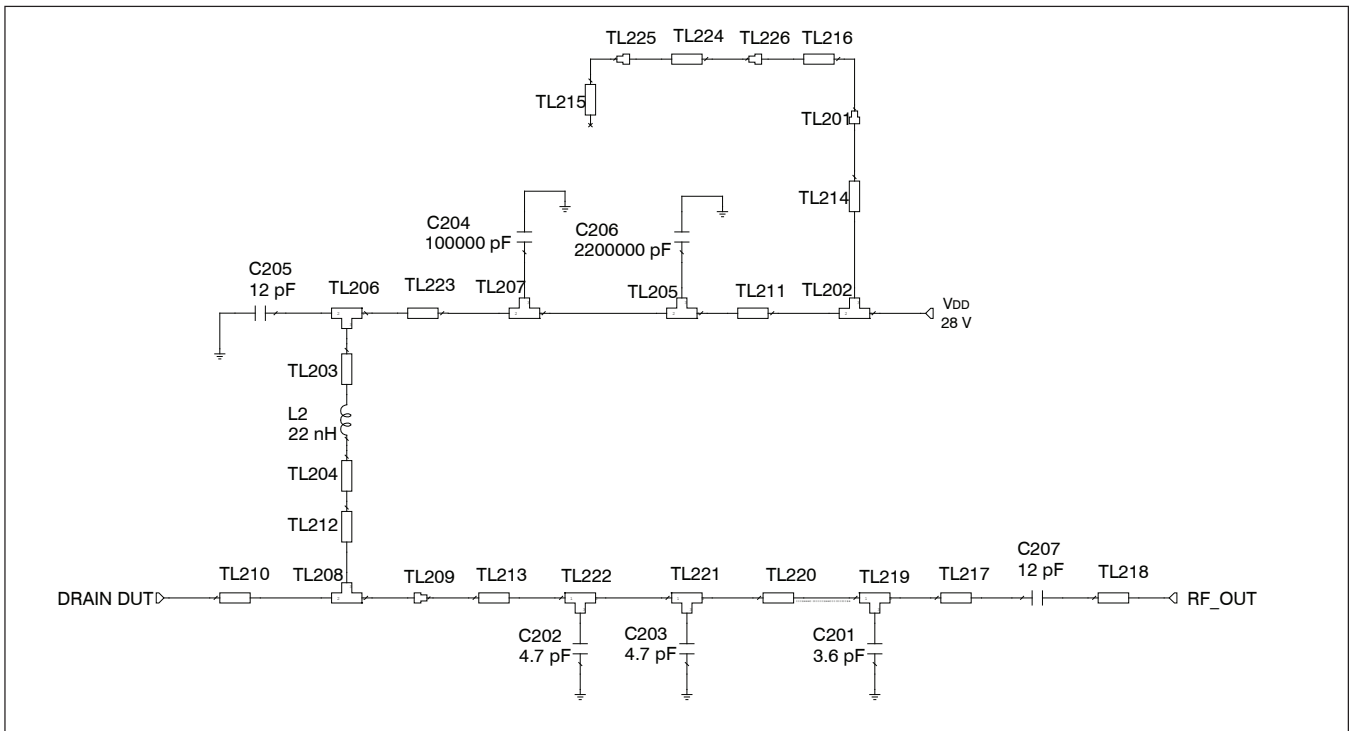
Frequency MHz	Z Source Ω		Z Load Ω	
	R	jX	R	jX
720	2.4	16.9	45.2	25.2
820	1.8	13.4	31.0	15.2
869	1.6	11.8	21.3	18.2
894	1.6	12.0	22.1	18.4
920	1.6	10.6	14.5	21.5
940	1.6	10.1	15.2	21.4
960	1.6	10.3	16.1	18.9
1805	2.1	3.2	6.8	12.1
1880	2.1	2.2	6.4	10.9
1930	1.8	1.3	6.3	10.6
1990	2.1	1.5	4.3	8.1
2110	2.5	2.0	4.9	8.4
2170	2.0	2.0	4.4	8.8



Reference Circuit, 1842 MHz



Reference circuit input schematic for $f = 1842$ MHz



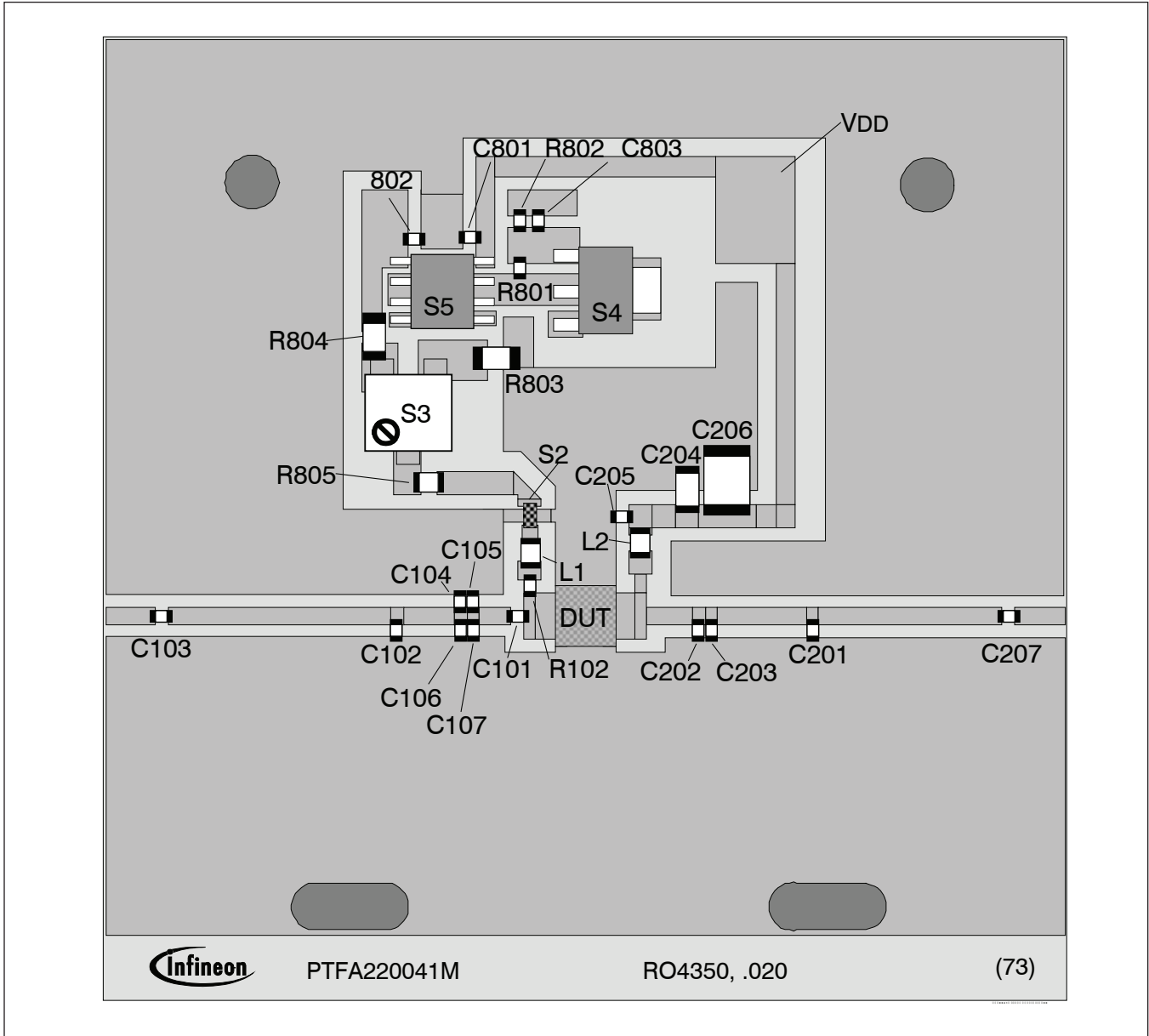
Reference circuit output schematic for $f = 1842$ MHz

Reference Circuit, 1842 MHz (cont.)
Electrical Characteristics at 1842 MHz

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
Input			
TL101	0.005 λ , 41.75 Ω	W = 1.524, L = 0.508	W = 60, L = 20
TL102	0.021 λ , 51.98 Ω	W = 1.087, L = 2.108	W = 43, L = 83
TL103		W = 1.524	W = 60
TL104	0.019 λ , 25.04 Ω	W = 3.048, L = 1.778	W = 120, L = 70
TL105	0.052 λ , 41.75 Ω	W = 1.524, L = 5.08	W = 60, L = 200
TL106	0.013 λ , 41.75 Ω	W = 1.524, L = 1.27	W = 60, L = 50
TL107	0.015 λ , 54.17 Ω	W = 1.016, L = 1.524	W = 40, L = 60
TL108	0.033 λ , 51.98 Ω	W = 1.087, L = 3.264	W = 43, L = 129
TL109	0.149 λ , 51.98 Ω	W = 1.087, L = 14.681	W = 43, L = 578
TL110	0.034 λ , 51.98 Ω	W = 1.087, L = 3.378	W = 43, L = 133
TL111	0.008 λ , 51.98 Ω	W1 = 1.087, W2 = 1.087, W3 = 0.813	W1 = 43, W2 = 43, W3 = 32
TL112, TL113, TL115, TL116		W = 0, L = 0	W = 0, L = 0
TL114, TL 117		W1 = 1.087, W2 = 0.813, W3 = 1.087 W4 = 0.813	W1 = 43, W2 = 32, W3 = 43, W4 = 32
TL118		W1 = 3.048, W2 = 0.762, W3 = 3.048, W4 = 0.762	W1 = 120, W2 = 30, W3 = 120, W4 = 30
Output			
TL201, TL225, TL226		W1 = 0.025, W2 = 0.025	W1 = 1, W2 = 1
TL202	0.013 λ , 41.75 Ω	W1 = 1.524, W2 = 1.524, W3 = 1.27	W1 = 60, W2 = 60, W3 = 50
TL203	0.005 λ , 41.75 Ω	W = 1.524, L = 0.508	W = 60, L = 20
TL204	0.016 λ , 41.75 Ω	W = 1.524, L = 1.524	W = 60, L = 60
TL205	0.039 λ , 41.75 Ω	W1 = 1.524, W2 = 1.524, W3 = 3.81	W1 = 60, W2 = 60, W3 = 150
TL206, TL207	0.016 λ , 41.75 Ω	W1 = 1.524, W2 = 1.524, W3 = 1.524	W1 = 60, W2 = 60, W3 = 60
TL208	0.008 λ , 25.04 Ω	W1 = 3.048, W2 = 3.048, W3 = 0.762	W1 = 120, W2 = 120, W3 = 30
TL209		W = 1.087, W2 = 3.048	W = 43, W2 = 120
TL210	0.019 λ , 25.04 Ω	W = 3.048, L = 1.778	W = 120, L = 70
TL211	0.014 λ , 41.75 Ω	W = 1.524, L = 1.346	W = 60, L = 53
TL212	0.013 λ , 63.89 Ω	W = 0.762, L = 1.27	W = 30, L = 50
TL213	0.031 λ , 51.98 Ω	W = 1.087, L = 3.073	W = 43, L = 121
TL214	0.163 λ , 47.12 Ω	W = 1.27, L = 15.926	W = 50, L = 627
TL215	0.074 λ , 47.12 Ω	W = 1.27, L = 7.29	W = 50, L = 287
TL216	0.076 λ , 15.92 Ω	W = 5.283, L = 6.986	W = 208, L = 275
TL217	0.123 λ , 51.98 Ω	W = 1.087, L = 12.103	W = 43, L = 477
TL218	0.033 λ , 51.98 Ω	W = 1.087, L = 3.264	W = 43, L = 129
TL219, TL221, TL222	0.008 λ , 51.98 Ω	W1 = 1.087, W2 = 1.087, W3 = 0.813	W1 = 43, W2 = 43, W3 = 32
TL220	0.060 λ , 51.98 Ω	W = 1.087, L = 5.867	W = 43, L = 231
TL223	0.016 λ , 41.75 Ω	W = 1.524, L = 1.524	W = 60, L = 60
TL224	0.149 λ , 47.12 Ω	W = 1.27, L = 14.554	W = 50, L = 573

Table continued next page

Reference Circuit, 1842 MHz (cont.)



Reference circuit assembly diagram (not to scale)*

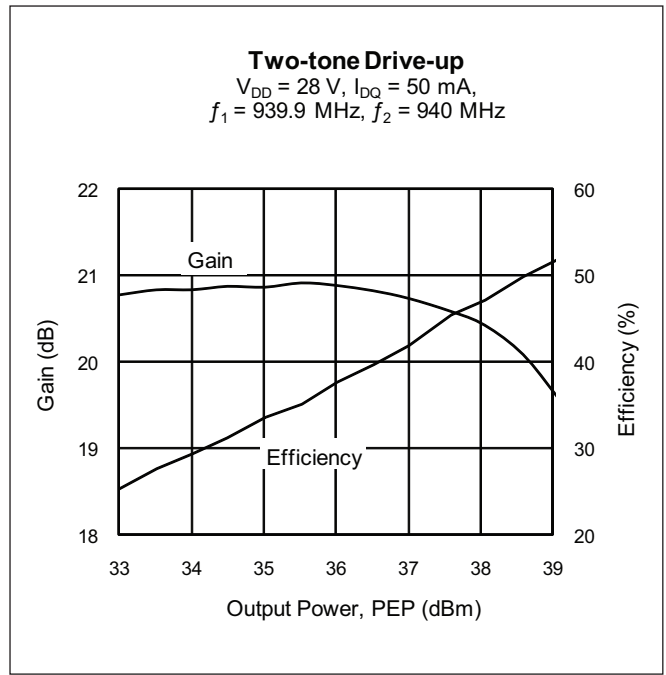
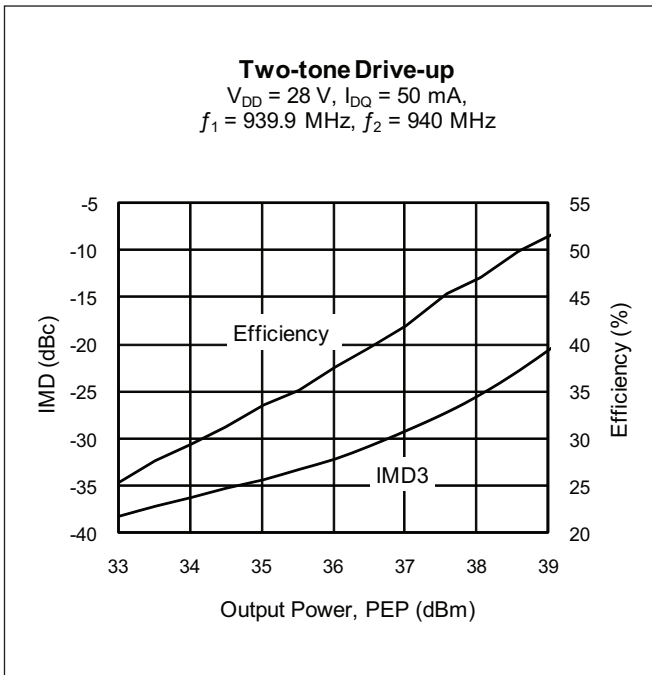
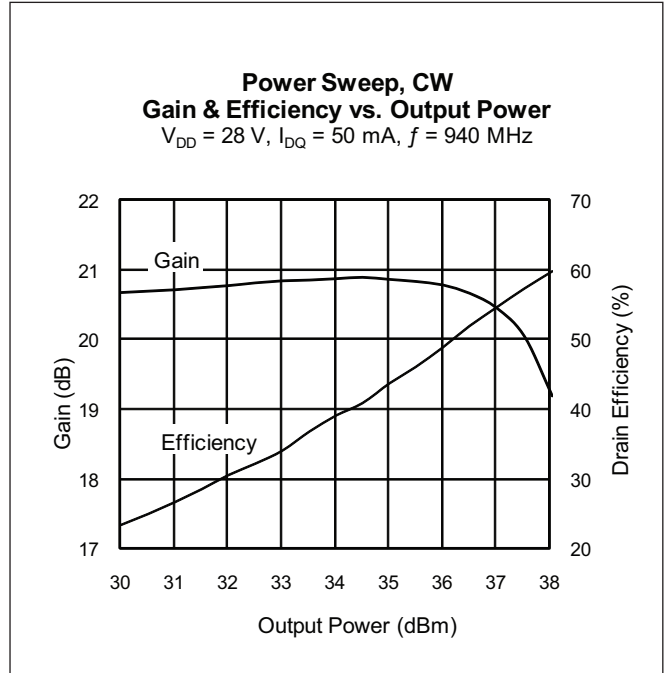
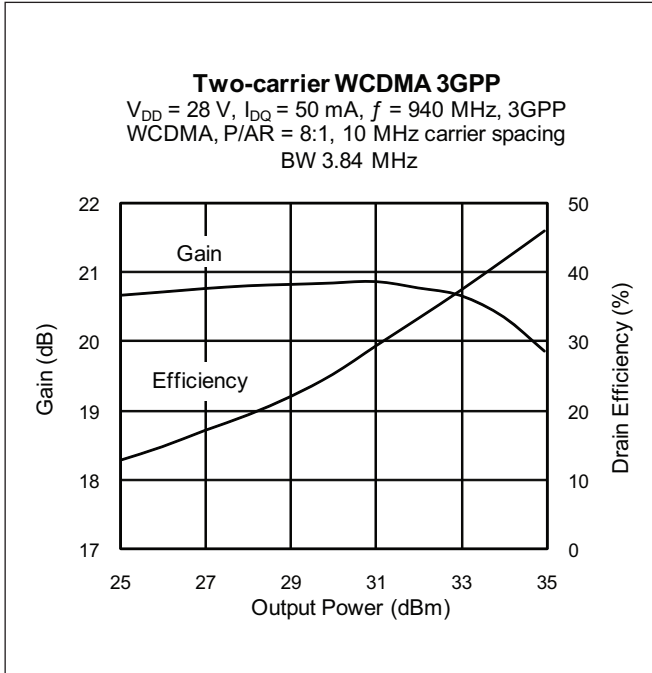
Reference Circuit, 1842 MHz (cont.)
Circuit Assembly Information

DUT	PTFA220041M	LDMOS Transistor	
PCB	LTN/PTFA220041M	0.508 mm [.020"] thick, $\epsilon_r = 3.48$	Rogers 4350, 1 oz. copper

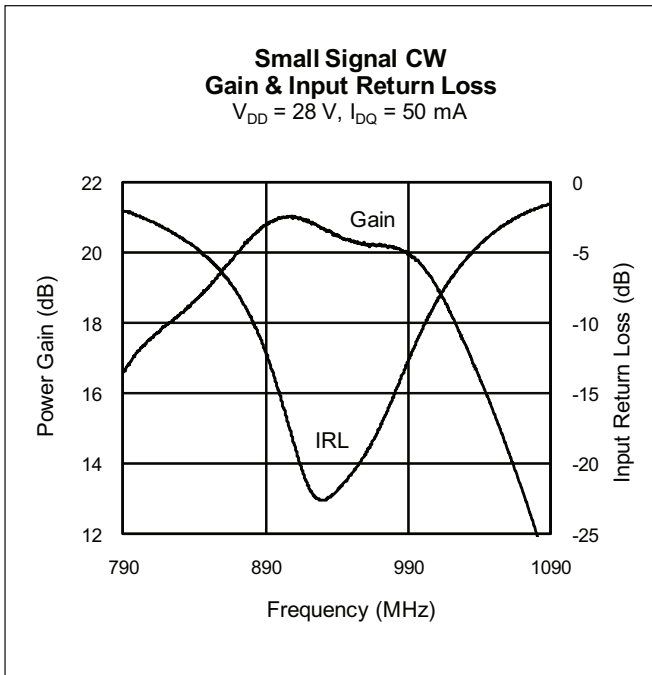
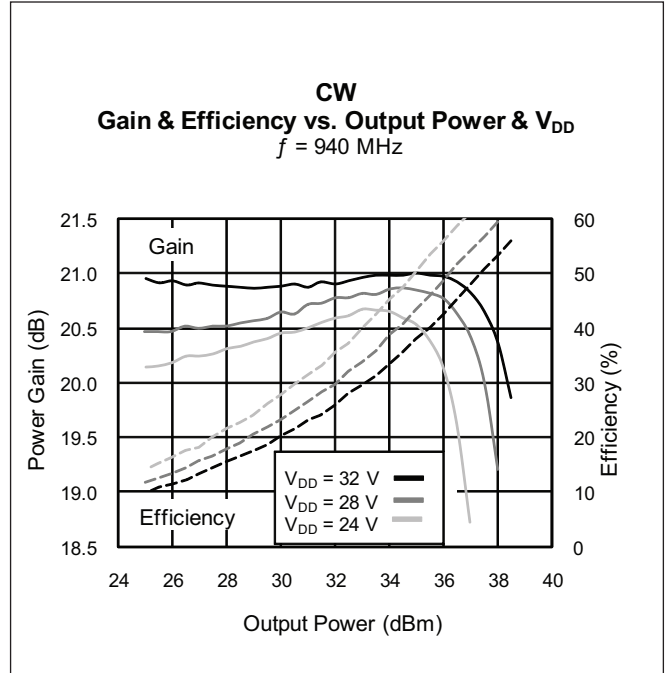
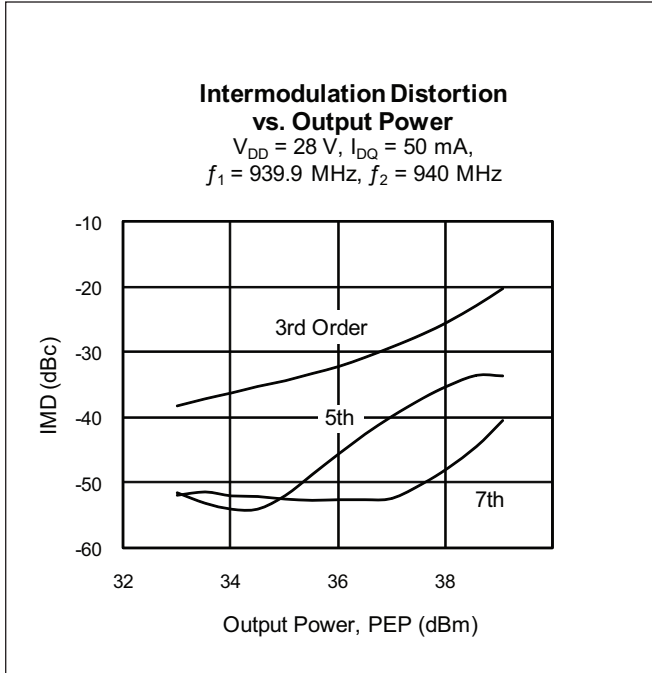
Component	Description	Suggested Manufacturer	P/N
Input			
C101	Chip capacitor, 6.2 pF	ATC	100A6R2CW150X
C102	Chip capacitor, 4.7 pF	ATC	100A4R7CW150X
C103	Chip capacitor, 12 pF	ATC	100A120JW150X
C104, C105, C106, C107	Chip capacitor, 7.5 pF	ATC	100A7R5CW150X
C801, C802, C803	Chip capacitor, 1.0 μ F	Digi-Key	445-1411-2-ND
L1	Inductor, 22 nH	Coilcraft	0805HT-22NX_BG
R102, R805	Resistor, 10 Ω	Digi-Key	P10ECT-ND
R801	Resistor, 1200 Ω	Digi-Key	P1.2KECT-ND
R802	Resistor, 1300 Ω	Digi-Key	P1.3KECT-ND
R803	Resistor, 500 Ω	Digi-Key	P500ECT-ND
R804	Resistor, 2000 Ω	Digi-Key	P2.0KECT-ND
S2	EMI Suppression Capacitor	Murata	NFM18PS105R0J3
S3	Potentiometer, 2k Ω	Digi-Key	3224W-202ECT-ND
S4	Transistor	Infineon Technologies	BCP56
S5	Voltage regulator	National Semiconductor	LM7805

Output			
C201	Chip capacitor, 3.6 pF	ATC	100A3R6CW150X
C202, C203	Chip capacitor, 4.7 pF	ATC	100A4R7CW150X
C204	Chip capacitor, 0.1 μ F	Digi-Key	PCC104BCT-ND
C205, C207	Chip capacitor, 12 pF	ATC	100A120JW150X
C206	Chip capacitor, 2.2 μ F	Digi-Key	445-1447-2-ND
L2	Inductor, 22 nH	Coilcraft	0805HT-22NX_BG

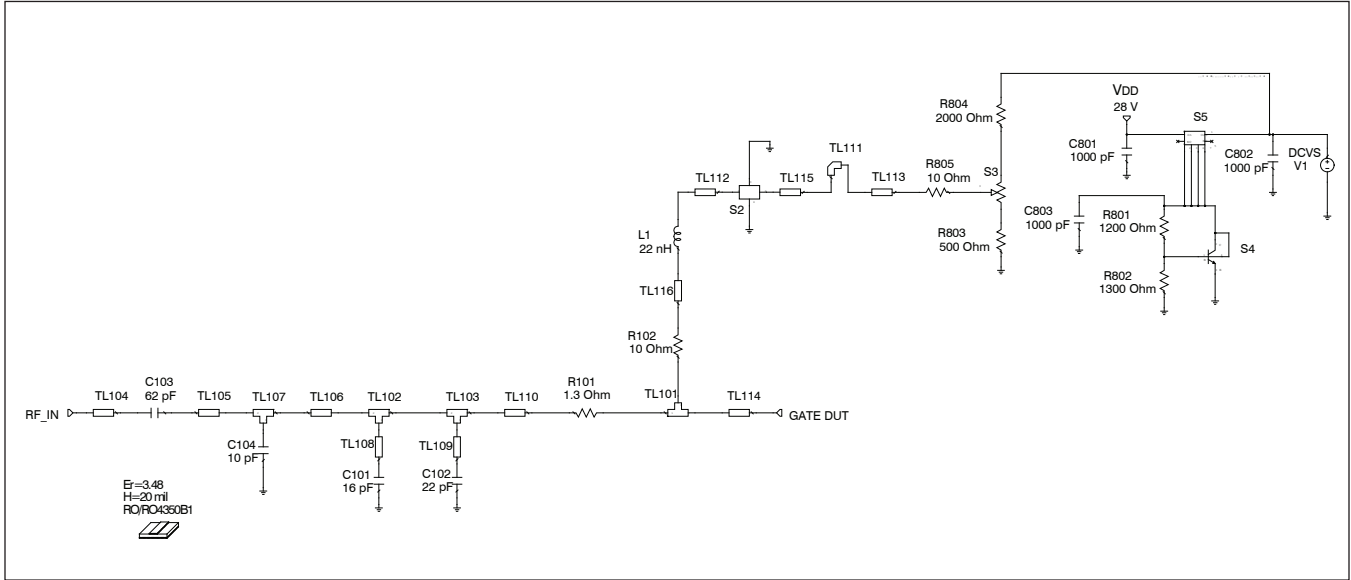
Typical Performance, 940 MHz



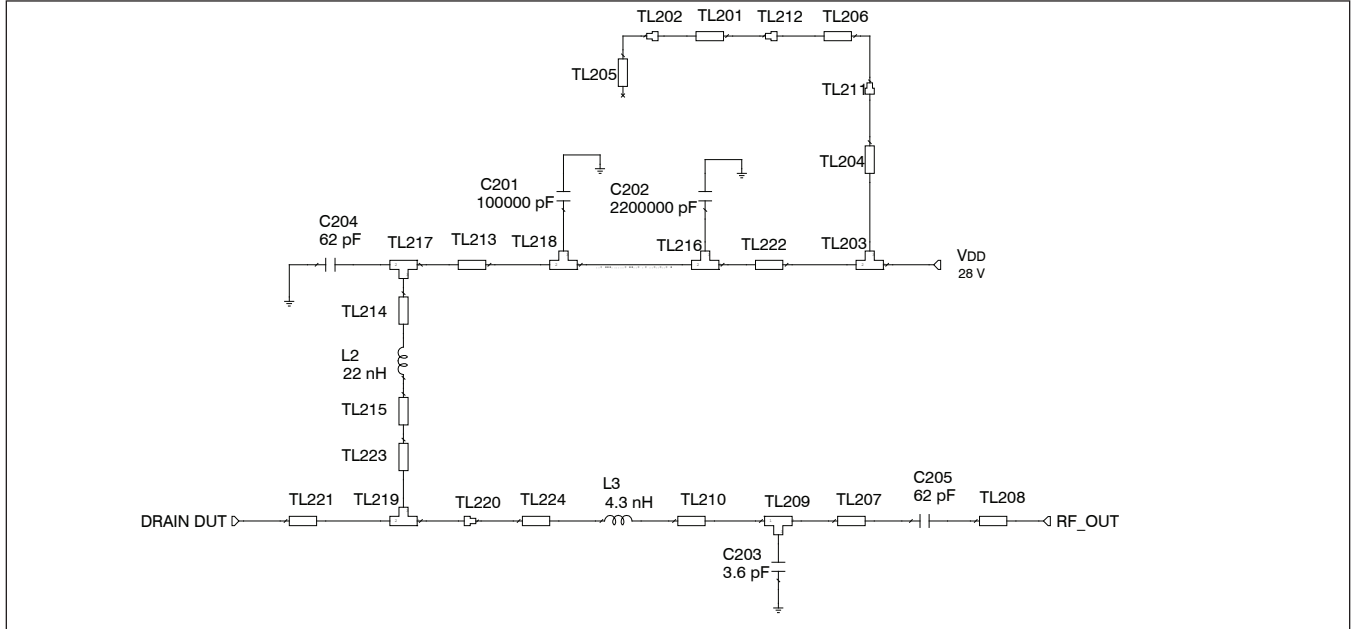
Typical Performance, 940 MHz (cont.)



Reference Circuit, 940 MHz



Reference circuit input schematic for $f = 940$ MHz



Reference circuit output schematic for $f = 940$ MHz

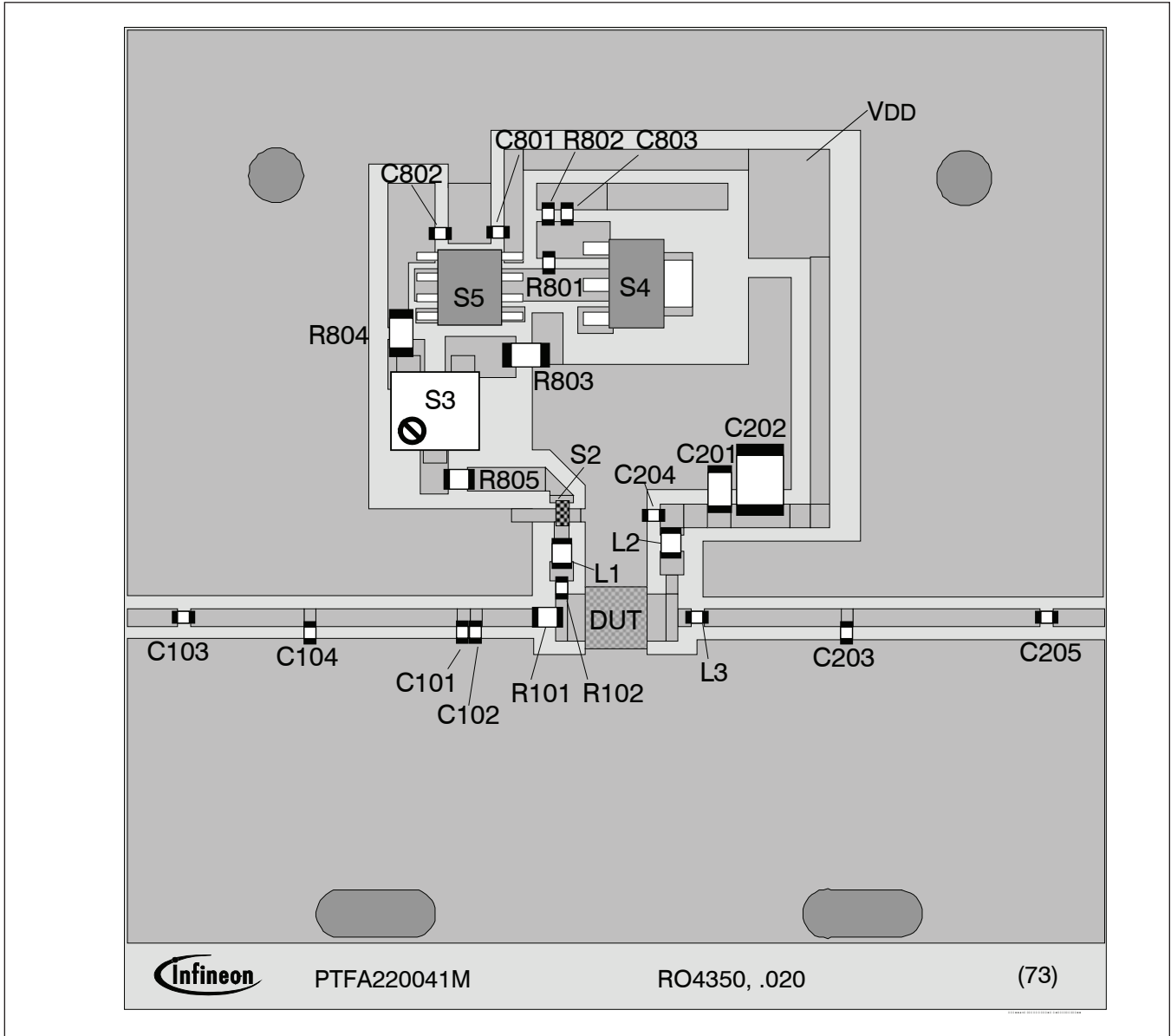
Reference Circuit, 940 MHz (cont.)

Electrical Characteristics at 940 MHz

Transmission Line	Electrical Characteristics	Dimensions: mm	Dimensions: mils
Input			
TL101	0.004 λ , 24.85 Ω	W1 = 3.048, W2 = 3.048, W3 = 0.762	W1 = 120, W2 = 120, W3 = 30
TL102, TL103	0.004 λ , 51.66 Ω	W1 = 1.087, W2 = 1.087, W3 = 0.813	W1 = 43, W2 = 43, W3 = 32
TL104	0.017 λ , 51.66 Ω	W = 1.087, L = 3.264	W = 43, L = 129
TL105	0.038 λ , 51.66 Ω	W = 1.087, L = 7.341	W = 43, L = 289
TL106	0.047 λ , 51.66 Ω	W = 1.087, L = 9.144	W = 43, L = 360
TL107	0.004 λ , 51.66 Ω	W1 = 1.087, W2 = 1.087, W3 = 0.762,	W1 = 43, W2 = 43, W3 = 30
TL108, TL109	0.000 λ , 144.28 Ω	W = 0.025, L = 0.000	W = 1, L = 0
TL110	0.019 λ , 51.66 Ω	W = 1.087, L = 3.734	W = 43, L = 147
TL111		W = 1.524	W = 60
TL112	0.008 λ , 53.85 Ω	W = 1.016, L = 1.524	W = 40, L = 60
TL113	0.027 λ , 41.47 Ω	W = 1.524, L = 5.080	W = 60, L = 200
TL114	0.010 λ , 24.85 Ω	W = 3.048, L = 1.778	W = 120, L = 70
TL115	0.003 λ , 41.47 Ω	W = 1.524, L = 0.508	W = 60, L = 20
TL116	0.007 λ , 41.47 Ω	W = 1.524, L = 1.270	W = 60, L = 50
Output			
TL201	0.076 λ , 46.82 Ω	W = 1.270, L = 14.554	W = 50, L = 573
TL202		W1 = 0.025, W2 = 0.025	W1 = 1, W2 = 1
TL203	0.007 λ , 41.47 Ω	W1 = 1.524, W2 = 1.524, W3 = 1.270	W1 = 60, W2 = 60, W3 = 50
TL204	0.083 λ , 46.82 Ω	W = 1.270, L = 15.927	W = 50, L = 627
TL205	0.038 λ , 46.82 Ω	W = 1.270, L = 7.290	W = 50, L = 287
TL206	0.039 λ , 15.79 Ω	W = 5.283, L = 6.986	W = 208, L = 275
TL207	0.063 λ , 51.66 Ω	W = 1.087, L = 12.103	W = 43, L = 477
TL208	0.017 λ , 51.66 Ω	W = 1.087, L = 3.264	W = 43, L = 129
TL209	0.004 λ , 51.66 Ω	W1 = 1.087, W2 = 1.087, W3 = 0.813	W1 = 43, W2 = 43, W3 = 32
TL210	0.046 λ , 51.66 Ω	W = 1.087, L = 8.852	W = 43, L = 349
TL211, TL212		W1 = 0.025, W2 = 0.025	W1 = 1, W2 = 1
TL213, TL215	0.008 λ , 41.47 Ω	W = 1.524, L = 1.524	W = 60, L = 60
TL214	0.003 λ , 41.47 Ω	W = 1.524, L = 0.508	W = 60, L = 20
TL216	0.020 λ , 41.47 Ω	W1 = 1.524, W2 = 1.524, W3 = 3.810	W1 = 60, W2 = 60, W3 = 150
TL217, TL218	0.008 λ , 41.47 Ω	W1 = 1.524, W2 = 1.524, W3 = 1.524	W1 = 60, W2 = 60, W3 = 60
TL219	0.004 λ , 24.85 Ω	W1 = 3.048, W2 = 3.048, W3 = 0.762	W1 = 120, W2 = 120, W3 = 30
TL220		W1 = 1.087, W2 = 3.048	W1 = 43, W2 = 120
TL221	0.010 λ , 24.85 Ω	W = 3.048, L = 1.778	W = 120, L = 70
TL222	0.007 λ , 41.47 Ω	W = 1.524, L = 1.346	W = 60, L = 53
TL223	0.007 λ , 63.55 Ω	W = 0.762, L = 1.270	W = 30, L = 50
TL224	0.004 λ , 51.66 Ω	W = 1.087, L = 0.851	W = 43, L = 33

Table continued next page

Reference Circuit, 940 MHz (cont.)



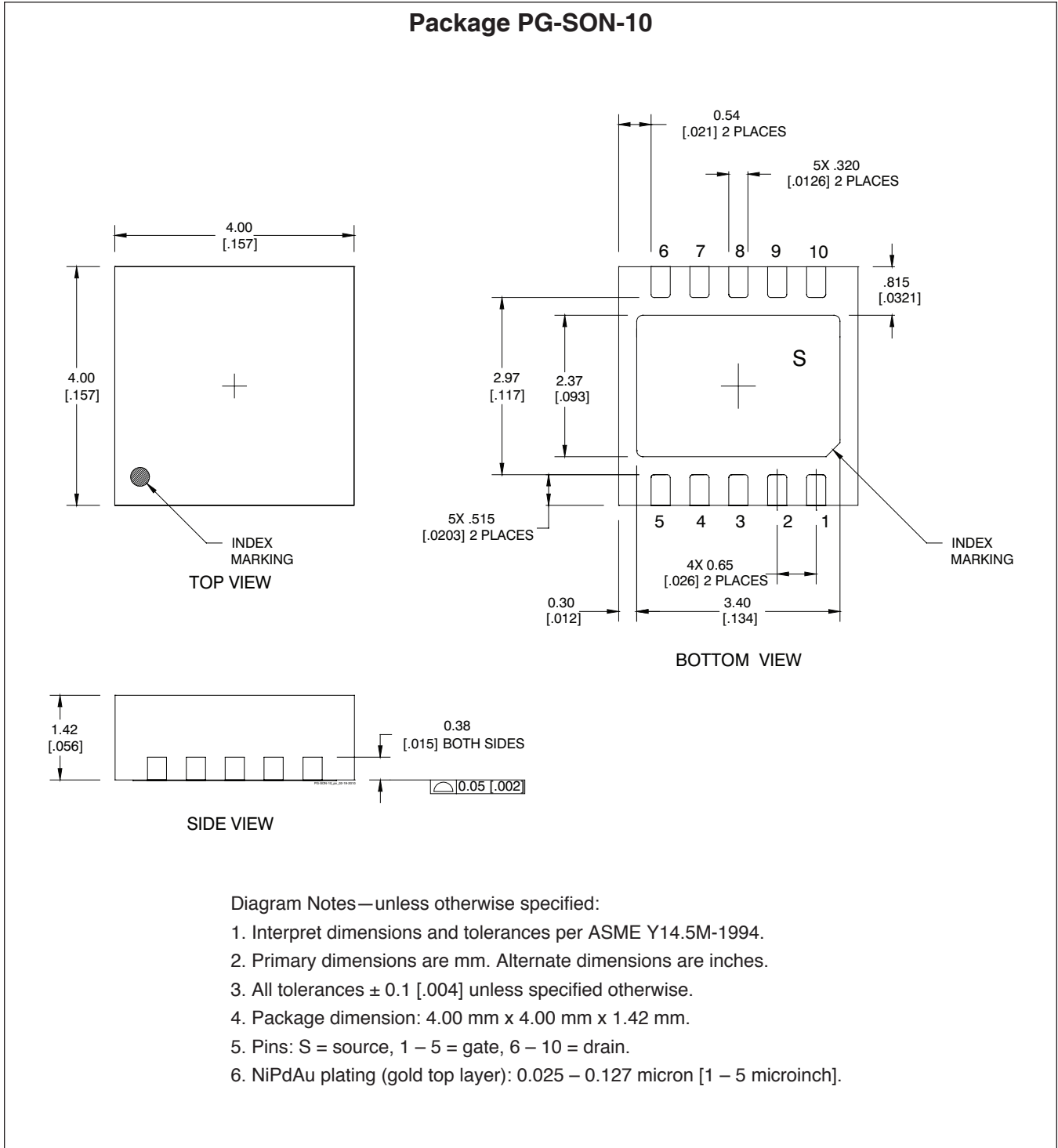
Reference circuit assembly diagram (not to scale)*

Reference Circuit, 940 MHz (cont.)
Circuit Assembly Information

DUT	PTFA220041M	LDMOS Transistor	
PCB	LTN/PTFA220041M-9	0.508 mm [.020"] thick, $\epsilon_r = 3.48$	Rogers 4350, 1 oz. copper

Component	Description	Suggested Manufacturer	P/N
Input			
C101	Chip capacitor, 16 pF	ATC	100A160JW150X
C102	Chip capacitor, 22 pF	ATC	100A220JW150X
C103	Chip capacitor, 62 pF	ATC	100A620JW150X
C104	Chip capacitor, 10 pF	ATC	100A100JW150X
C801, C802, C803	Chip capacitor, 1000 pF	Digi-Key	PCC1772CT-ND
L1	Inductor, 22 nH	Coilcraft	0805HT-22NX_BG
R101	Resistor, 1.3 Ω	Digi-Key	P1.3ECT-ND
R102, R805	Resistor, 10 Ω	Digi-Key	P10ECT-ND
R801	Resistor, 1200 Ω	Digi-Key	P1.2KECT-ND
R802	Resistor, 1300 Ω	Digi-Key	P1.3KECT-ND
R803	Resistor, 500 Ω	Digi-Key	P5.0KECT-ND
R804	Resistor, 2000 Ω	Digi-Key	P2.0KECT-ND
S2	EMI Suppression Capacitor	Murata	NFM18PS105R0J3
S3	Potentiometer, 2k Ω	Digi-Key	3224W-202ECT-ND
S4	Transistor	Infineon Technologies	BCP56
S5	Voltage Regulator	National Semiconductor	LM7805
Output			
C201	Chip capacitor, 0.1 μF	Digi-Key	PCC104BCT-ND
C202	Chip capacitor, 2.2 μF	Digi-Key	445-1447-2-ND
C203	Chip capacitor, 3.6 pF	ATC	100A3R6CW150X
C204, C205	Chip capacitor, 62 pF	ATC	100A620JW150X
L2	Inductor, 22 nH	Coilcraft	0805HT-22NX_BG
L3	Inductor, 4.3 nH	Coilcraft	0603CS-4N3X_BG

Package Outline Specifications



Find the latest and most complete information about products and packaging at the Infineon Internet page <http://www.infineon.com/rfpower>

Revision History: 2010-06-07 Data Sheet

Previous Version: 2010-04-15, Data Sheet

Page	Subjects (major changes since last revision)
6	Updated broadband circuit impedance

We Listen to Your Comments

Any information within this document that you feel is wrong, unclear or missing at all?

Your feedback will help us to continuously improve the quality of this document.

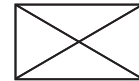
Please send your proposal (including a reference to this document) to:

highpowerRF@infineon.com

To request other information, contact us at:

+1 877 465 3667 (1-877-GO-LDMOS) USA

or +1 408 776 0600 International



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For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com/rfpower).

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